Remarks:

This Amendment and the accompanying Request for Continued Examination are being filed responsive to the March 2, 2006 final Office action that was issued in connection with the above-identified patent application.

Prior to entry of this Amendment, claims 1-7 remained pending in the application, claims 8-24 having been cancelled pursuant to an earlier restriction requirement. Claims 1-2 and 4-7 stands rejected under 35 U.S.C. § 102(b) based on Voss et al. (US 4,322,449). Claim 3 stands rejected under 35 U.S.C. § 103(a) based on Voss et al. in view of Vogues (US 5,894,841). Applicants respectfully disagree with the rejections.

Nevertheless, in the interest of furthering prosecution of this application to issuance of a patent, and in view of a telephone conference with the Examiner on April 17, 2006, applicants have amended claim 1 to make the recited "**target** dissolution rate" more clear. Based on the aforementioned April 17, 2006 telephone conference with the Examiner, it is believed that the present amendments will result in a more accurate understanding of applicants' claims.

In rejecting applicants' claims, the Examiner has asserted that "controlling the dot pattern, the shape or size of the dot, or the consistency of the size of the dots will inherently provide control over the dissolution rate." The Examiner has thus far **not**

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considered the selection of a dot topography based on a particular **target** dissolution rate. The Examiner indicates only that controlling parameters that affect dot topography will inherently also affect dissolution rate.

By this amendment, applicants have amended claim 1 to recite "identifying a target dissolution rate," making it more clear that the desired dot topography is selected to correspond to the identified target dissolution rate. The recited selection of dot topography thus is not one that is inherent in controlling particular parameters, but rather, is made based on an identified target dissolution rate so as to achieve the identified target dissolution rate.

Regarding the cited references, applicants note that neither Voss et al. nor Voges disclose selection of a dot topography to achieve a particularly identified target dissolution rate. In fact, neither Voss et al. nor Voges disclose any identification of a target dissolution rate. By the Examiner's own characterization, Voss discloses nothing more than forming dots on a delivery substrate in a desired geometric pattern. There is absolutely no discussion of dissolution rate. Voges is cited only as teaching inkjet printing using piezoelectric ejection elements or thermal ejection elements.

Also in view of the foregoing, applicants have added new claims 25-29, which claims also are distinguished from Voss et al. and Voges.

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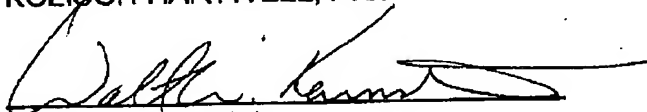   HP Docket No. 200401492-1
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Conclusion

Applicants believe that this application is now in condition for allowance, in view of the above amendments and remarks. Accordingly, applicants respectfully request that the Examiner issue a Notice of Allowability covering the pending claims. If the Examiner has any questions, or if a telephone interview would in any way advance prosecution of the application, please contact the undersigned attorney of record.
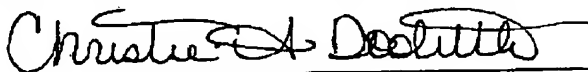
Respectfully submitted,

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CERTIFICATE OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being facsimile transmitted to Examiner J. Michener, Group Art Unit 1762, Assistant Commissioner for Patents, at facsimile number (571) 273-8300 on June 2, 2006.

Christie A. Doolittle

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